

**Absolute Maximum Ratings**

Drain-to-Source Voltage ..... -6V  
 Gate-to-Source Voltage ..... -6V  
 Continuous Drain Current  
    $T_A = 25^\circ\text{C}$  ( $V_{GS} = 4.5\text{V}$ ) ..... 1.8A  
    $T_A = 100^\circ\text{C}$  ( $V_{GS} = 4.5\text{V}$ ) ..... 1.2A  
 Total Power Dissipation  
    $T_A = 25^\circ\text{C}$  ..... 568mW  
    $T_A = 100^\circ\text{C}$  ..... 227mW  
 Operating Junction Temperature .....  $-40^\circ\text{C}$  to  $+150^\circ\text{C}$   
 Storage Temperature .....  $-55^\circ\text{C}$  to  $+150^\circ\text{C}$   
 ESD Rating, **Note 2**


**Operating Ratings**

Thermal Resistance  
    $\theta_{JA}$  .....  $220^\circ\text{C/W}$   
    $\theta_{JC}$  .....  $130^\circ\text{C/W}$

**Electrical Characteristics (Note 1)**

Symbol	Parameter	Condition (Note 1)	Min	Typ	Max	Units
$V_{GS}$	Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = -250\mu\text{A}$	0.5		1.2	V
$I_{GSS}$	Gate-Body Leakage	$V_{DS} = 0\text{V}$ , $V_{GS} = -4.5\text{V}$ , <b>Note 2, Note 3</b>			1	$\mu\text{A}$
$R_{GS}$	Gate-Source Resistance	$V_{DS} = 0\text{V}$ , $V_{GS} = -4.5\text{V}$ , <b>Note 2, Note 4</b>	200	350	500	k $\Omega$
$C_{ISS}$	Input Capacitance	$V_{GS} = 0\text{V}$ , $V_{DS} = -5.5\text{V}$		600		pF
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = -5.5\text{V}$ , $V_{GS} = 0\text{V}$			1	$\mu\text{A}$
		$V_{DS} = -5.5\text{V}$ , $V_{GS} = 0\text{V}$ , $T_J = 85^\circ\text{C}$			5	$\mu\text{A}$
$R_{DS(ON)}$	Drain-Source On-Resistance	$V_{GS} = -4.5\text{V}$ , $I_D = -100\text{mA}$		0.125	0.160	$\Omega$
		$V_{GS} = -3.6\text{V}$ , $I_D = -100\text{mA}$		0.135	0.180	$\Omega$
		$V_{GS} = -2.5\text{V}$ , $I_D = -100\text{mA}$		0.165	0.200	$\Omega$
		$V_{GS} = -1.8\text{V}$ , $I_D = -100\text{mA}$		0.225	0.320	$\Omega$
$g_{FS}$	Forward Transconductance	$V_{DS} = -5.5\text{V}$ , $I_D = -200\text{mA}$ , <b>Note 5</b>		3		S

**Note 1.**  $T_A = 25^\circ\text{C}$  unless noted. Substrate connected to source for all conditions.

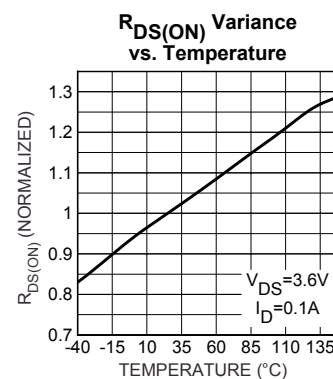
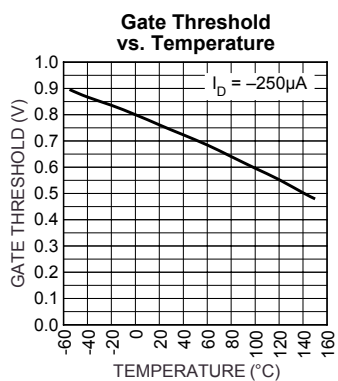
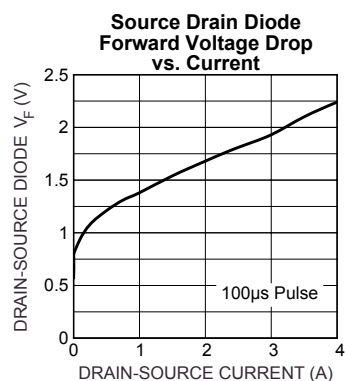
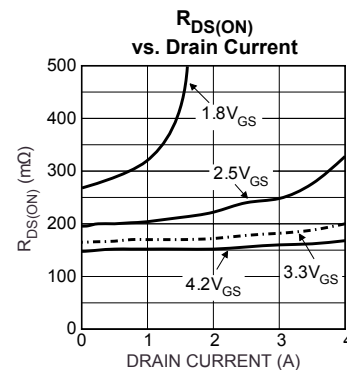
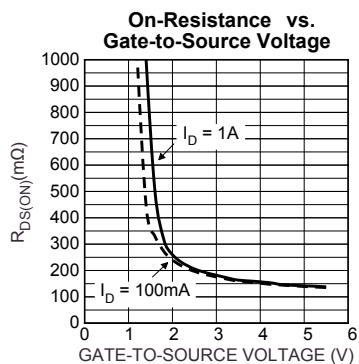
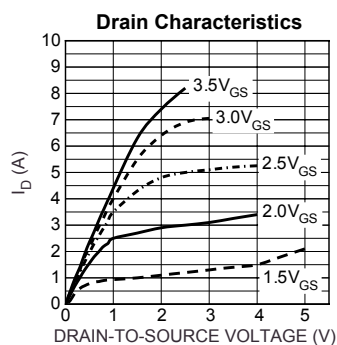
**Note 2.** ESD gate  precautions required

**Note 3.** MIC94050 only.

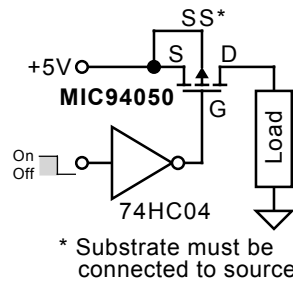
**Note 4.** MIC94051 only.

**Note 5.** Pulse Test: Pulse Width  $\leq 80\mu\text{s}$ , Duty Cycle  $\leq 0.5\%$ .

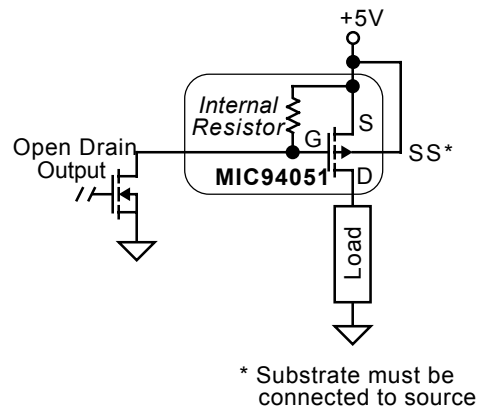
## Typical Characteristics



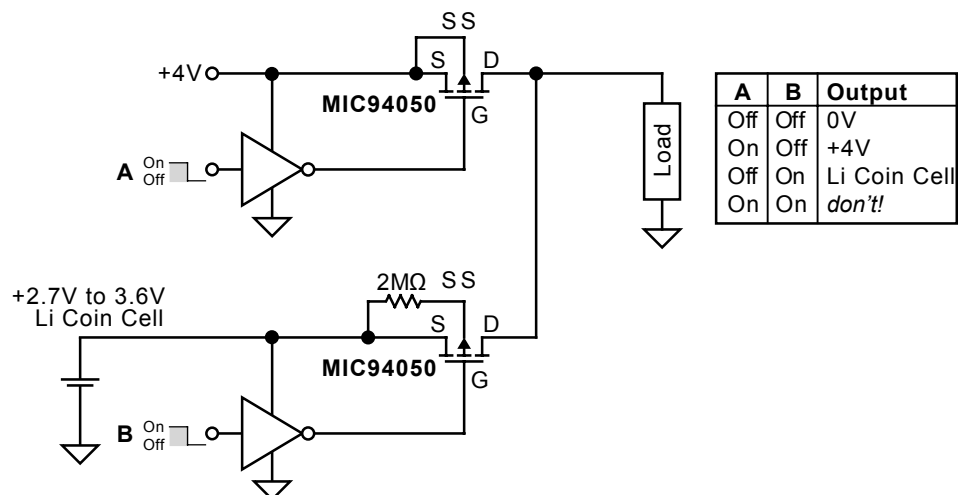
## Typical Applications



**Figure 1. Load Switch Application**

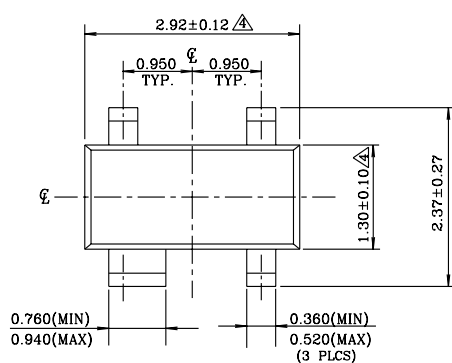


**Figure 2. Load Switch Application  
(with internal gate-source pull-up)**

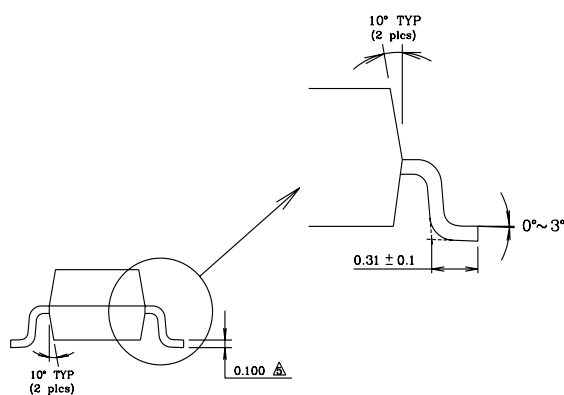


**Figure 3. Reverse-Blocking Battery Back-Up Application**

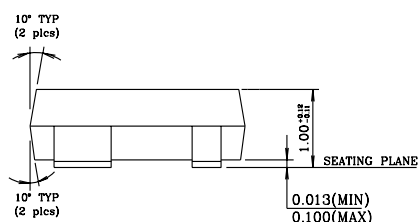
## Package Information



TOP VIEW



END VIEW



SIDE VIEW

## NOTE:

1. Dimensions and tolerances are as per ANSI Y14.5M, 1982.
  2. Package surface to be mirror finish.
  3. Die is facing up for mold & trim/form.
- △ Dimension are exclusive of mold flash and gate burr.  
 △ Dimension are exclusive of solder plating.

### SOT-143 (M4)

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